TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

2 S C 4 5 2 7

TV TUNER, UHF OSCILLATOR APPLICATIONS (COMMON BASE) TV TUNER, UHF CONVERTER APPLICATIONS (COMMON BASE)

- Transition Frequency is High and Dependent on Current Excellently.
- Exchange of Emitter for Base in 2SC4246.

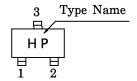
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V _{CBO}	30	V
Collector-Emitter Voltage	v_{CEO}	15	V
Emitter-Base Voltage	$ m V_{EBO}$	3	V
Base Current	I_{B}	25	mA
Collector Current	$I_{\mathbf{C}}$	50	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	100	mW
Junction Temperature	T_{j}	125	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	$^{\circ}\mathrm{C}$

Unit in mm .25 ± 0.1 2.0 ± 0.2 1.3 ± 0.1 0.65 0~0.1 1. EMITTER 2. BASE 3. COLLECTOR **JEDEC** EIAJ SC-70 **TOSHIBA** 2-2E1D

Weight: 0.006g

Marking



ELECTRICAL CHARACTERISTICS (Ta = 25°C)

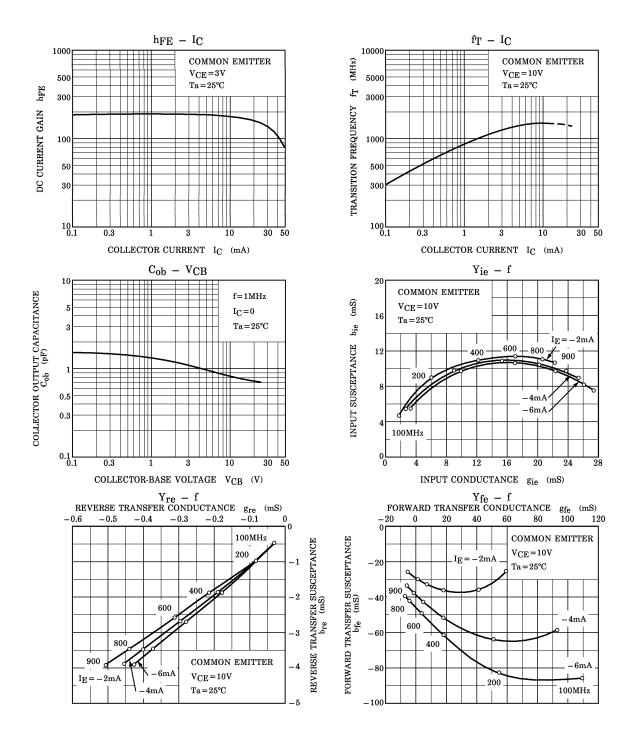
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT		
Collector Cut-off Current	I_{CBO}	$V_{CB} = 15V, I_{E} = 0$	_	_	0.1	μ A		
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB}=3V, I_{C}=0$	_	_	1.0	μ A		
Collector-Emitter Breakdown Voltage	V (BR) CEO	$I_C=1$ mA, $I_B=0$	15	_	_	v		
DC Current Gain	$_{ m h_{FE}}$	$V_{\rm CE}$ =3V, $I_{\rm C}$ =8mA	60	150	320	_		
Transition Frequency	${ m f_T}$	$V_{CE}=10V, I_{C}=8mA$	1100	1500	_	MHz		
Collector Output Capacitance	C_{ob}	$V_{CB} = 10V, I_E = 0, f = 1MHz$	_	0.9	1.3	рF		
Collector-Base Time Constant	C _c .rbb'	$V_{\text{CB}} = 10\text{V}, I_{\text{C}} = 8\text{mA},$ f = 30MHz	_	7	12	ps		

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TOSHIBA 2SC4527

